SHARP

PC900V0NSZX Series

Digital Output, Normal OFF Operation DIP 6 pin *OPIC Photocoupler



Description

PC900V0NSZX Series contains an IRED optically coupled to an OPIC chip.

It is packaged in a 6 pin DIP, available in SMT gullwing lead-form and Wide SMT gullwing lead-form option.

Input-output isolation voltage(rms) is 5.0kV.

Features

- 1.6 pin DIP package
- 2. Double transfer mold package (Ideal for Flow Soldering)
- 3. Normal OFF operation, open collector output
- 4. TTL and LSTTL compatible output
- 5. Operating supply voltage (V_{CC} : 3 to 15 V)
- 6. Isolation voltage (V_{iso(rms)} : 5.0 kV)

Agency approvals/Compliance

- 1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. **PC900V**)
- 2. Approved by TÜV (VDE0884) (as an option) file No. R9151577 (as model No. **PC900V**)
- 3. Package resin : UL flammability grade (94V-0)

Applications

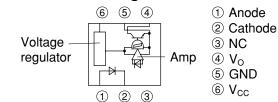
- 1. Programmable controllers
- 2. PC peripherals
- 3. Electronic musical instruments

* "OPIC"(Optical IC) is a trademark of the SHARP Corporation. An OPIC consists of a light-detecting element and a signal-processing circuit integrated onto a single chip.

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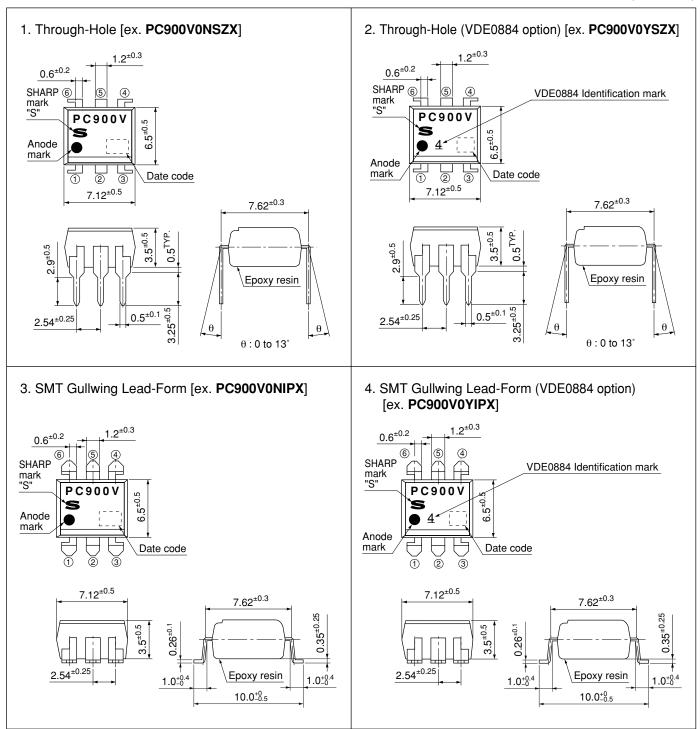


Internal Connection Diagram



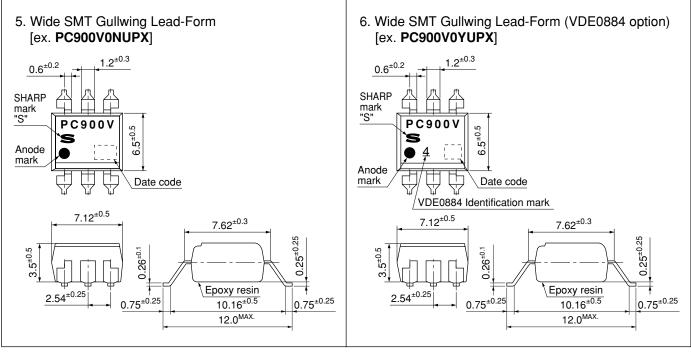
Outline Dimensions

(Unit : mm)





(Unit : mm)



Product mass : approx. 0.36g



Date code (2 digit)

			i .			
	1st o	digit		2nd digit		
	Year of p	roduction		Month of production		
A.D.	Mark	A.D	Mark	Month	Mark	
1990	A	2002	Р	January	1	
1991	В	2003	R	February	2	
1992	С	2004	S	March	3	
1993	D	2005	Т	April	4	
1994	Е	2006	U	May	5	
1995	F	2007	V	June	6	
1996	Н	2008	W	July	7	
1997	J	2009	Х	August	8	
1998	K	2010	А	September	9	
1999	L	2011	В	October	0	
2000	М	2012	С	November	N	
2001	N	:		December	D	

repeats in a 20 year cycle

Country of origin Japan

■ Absolute Maximum Ratings

	Parameter	Symbol	Rating	Unit
	Forward current	I_F	50	mA
Tanut	*1 Peak forward current	I _{FM}	1	А
Input	Reverse voltage	V _R	6	V
	Power dissipation	Р	70	mW
	Supply voltage	V _{CC}	16	V
Outmut	High level output voltage	V _{OH}	16	V
Output	Low level output current	I _{OL}	50	mA
	Power dissipation	Po	150	mW
Total power dissipation		P _{tot}	170	mW
Opera	ting temperature	T _{opr}	-25 to +85	°C
Storag	ge temperature	T _{stg}	-40 to +125	°C
*2 Isolation voltage		V _{iso (rms)}	5.0	kV
*3 Solde	ring temperature	T _{sol}	260	°C

*1 Pulse width≤100µs, Duty ratio : 0.001
*2 40 to 60%RH, AC for 1minute, f=60Hz

*3 For 10s

Electro-optical Characteristics

(Unless otherwise specified $T_a=0$ to $+70^{\circ}C$)

							0.00 . 7 0 . 0)		
		Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
			V	IF=4mA		1.1	1.4	V	
Input		Forward voltage	$V_{\rm F}$	$I_F=0.3mA$	0.7	1.0	-	v	
Int]	Reverse current	I _R	$T_a=25^{\circ}C, V_R=3V$	-	_	10	μΑ	
	5	Terminal capacitance	Ct	$T_a=25^{\circ}C$, V=0, f=1kHz	-	30	250	pF	
	(Operating Supply voltage	V _{CC}	_	3	-	15	V	
]	Low level output voltage	V _{OL}	I_{OL} =16mA, V_{CC} =5V, I_{F} =4mA	-	0.2	0.4	V	
]	High level output current	I _{OH}	$V_{O}=V_{CC}=15V, I_{F}=0$	-	-	100	μΑ	
]	Low level supply current	I _{CCL}	$V_{CC}=5V, I_F=4mA$	-	2.5	5.0	mA	
Ħ]	High level supply current	I _{CCH}	V _{CC} =5V, I _F =0	-	1.0	5.0	mA	
Output	*4 י	"High→Low" input	iput _	$T_a=25^{\circ}C, V_{CC}=5V, R_L=280\Omega$	-	1.1	2.0	•	
0	t	threshold current	I_{FHL}	$V_{CC}=5V, R_L=280\Omega$	-	-	4.0	mA	
	• 5*	"Low→High" input	т	$T_a=25^{\circ}C, V_{CC}=5V, R_L=280\Omega$	0.4	0.8	-	•	
	t	threshold current	I_{FLH}	$V_{CC}=5V, R_L=280\Omega$	0.3	-	-	mA	
	*6]	Hysteresis	I _{FLH} /I _{FHL}	$V_{CC}=5V, R_L=280\Omega$	0.5	0.7	0.9	-	
]	Isolation voltage	R _{ISO}	T _a =25°C, DC500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	-	Ω	
stics	time	"High→Low" propagation delay time	t _{PHL}		-	1	3		
racter	se ti	"Low→High" propagation delay time	t _{PLH}	$T_a=25^{\circ}C, V_{CC}=5V, I_F=4mA$	-	2	6		
Transfer characteristics	Rise time		t _r	$R_L=280\Omega$	-	0.1	0.5	μs	
Trans	Res	Fall time	t _f		-	0.05	0.5		

 $(T_a=25^{\circ}C)$

*4 I_{FHL} represents forward current when output goes from high to low. *5 I_{FLH} represents forward current when output goes from low to high. *6 Hysteresis stands for I_{FLH}/I_{FHL} .



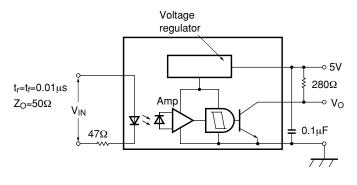
■ Model Line-up

Lead Form	Throug	gh-Hole		SMT G	ullwing		Wide SM7	Gullwing
Dealraga	Sleeve				Taping			
Package	50pcs/sleeve			1 000pcs/reel				
VDE0884		Approved		Approved		Approved		Approved
Model No.	PC900V0NSZX	PC900V0YSZX	PC900V0NIZX	PC900V0YIZX	PC900V0NIPX	PC900V0YIPX	PC900V0NUPX	PC900V0YUPX

Please contact a local SHARP sales representative to inquire about production status and Lead-Free options.



Fig.1 Test Circuit for Response Time



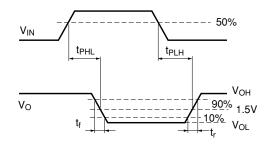
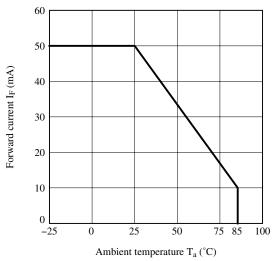
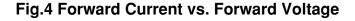


Fig.2 Forward Current vs. Ambient Temperature





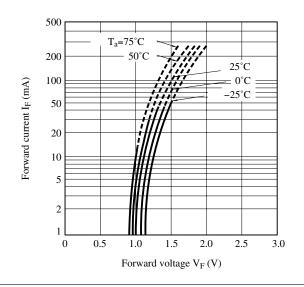


Fig.3 Power Dissipation vs. Ambient Temperature

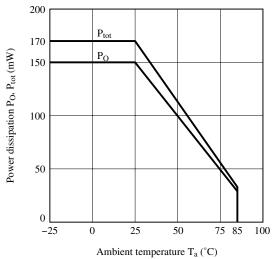


Fig.5 Relative Input Threshold Current vs. Supply Voltage

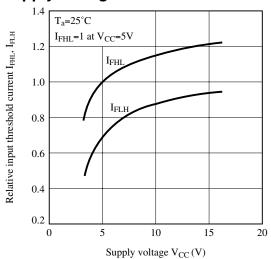
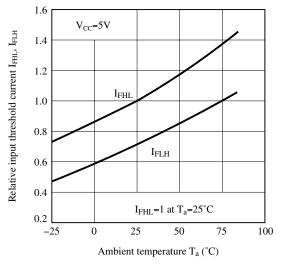
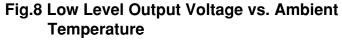




Fig.6 Relative Input Threshold Current vs. Ambient Temperature





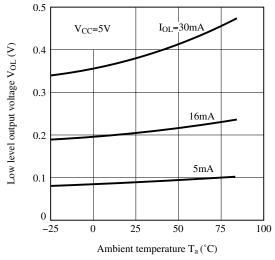


Fig.10 Propagation Delay Time vs. Forward Current

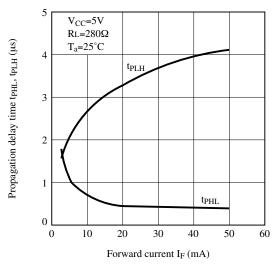


Fig.7 Low Level Output Voltage vs. Low Level Output Current

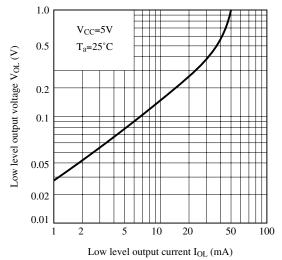


Fig.9 Supply Current vs. Supply Voltage

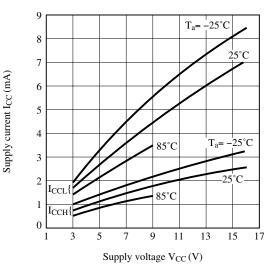
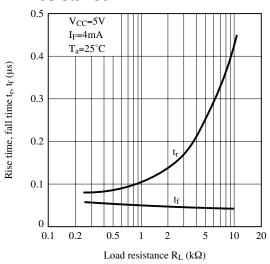


Fig.11 Rise Time, Fall Time vs. Load Resistance



Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.



Design Considerations

Notes about static electricity

Transistor of detector side in bipolar configuration may be damaged by static electricity due to its minute design.

When handling these devices, general countermeasure against static electricity should be taken to avoid breakdown of devices or degradation of characteristics.

• Design guide

In order to stabilize power supply line, we should certainly recommend to connect a by-pass capacitor of 0.01μ F or more between V_{CC} and GND near the device.

The detector which is used in this device, has parasitic diode between each pins and GND.

There are cases that miss operation or destruction possibly may be occurred if electric potential of any pin becomes below GND level even for instant.

Therefore it shall be recommended to design the circuit that electric potential of any pin does not become below GND level.

This product is not designed against irradiation and incorporates non-coherent IRED.

Degradation

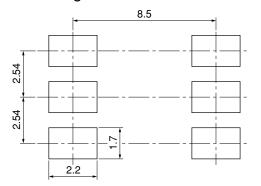
In general, the emission of the IRED used in photocouplers will degrade over time.

In the case of long term operation, please take the general IRED degradation (50% degradation over 5years) into the design consideration.

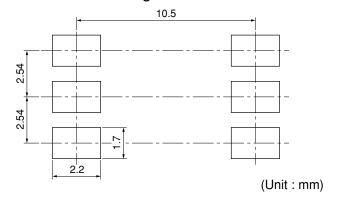
Please decide the input current which become 2times of MAX. IFHL.



• Recommended Foot Print (reference) SMT Gullwing Lead-form



Wide SMT Gullwing Lead-form



☆ For additional design assistance, please review our corresponding Optoelectronic Application Notes.

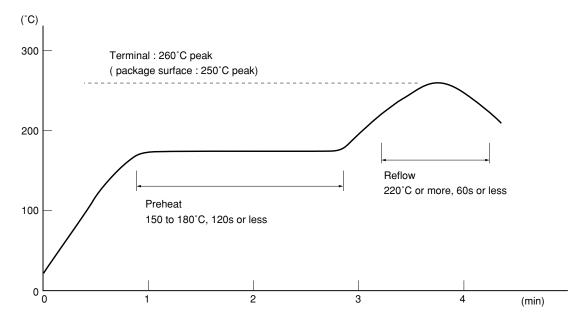


Manufacturing Guidelines

Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below. Soldering should not exceed the curve of temperature profile and time. Please don't solder more than twice.



Flow Soldering :

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s. Preheating is within the bounds of 100 to 150°C and 30 to 80s. Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C. Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



• Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below Immersion time should be 3minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

• Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this device.

Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform) Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.



Package specification

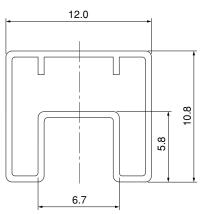
• Sleeve package

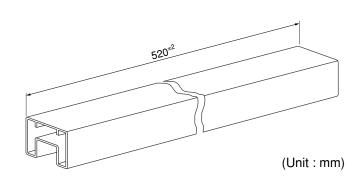
Package materials Sleeve : HIPS (with anti-static material) Stopper : Styrene-Elastomer

Package method

MAX. 50 pcs. of products shall be packaged in a sleeve.Both ends shall be closed by tabbed and tabless stoppers.The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.MAX. 20 sleeves in one case.

Sleeve outline dimensions



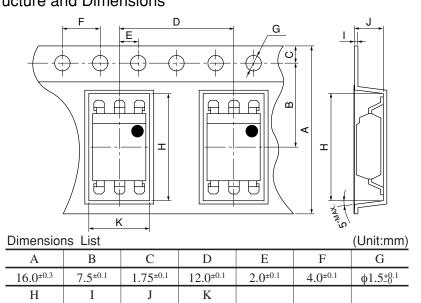




• Tape and Reel package

1. SMT Gullwing

Package materials Carrier tape : A-PET (with anti-static material) Cover tape : PET (three layer system) Reel : PS Carrier tape structure and Dimensions



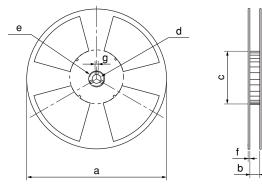
 $7.8^{\pm0.1}$

Reel structure and Dimensions

 $10.4^{\pm 0.1}$

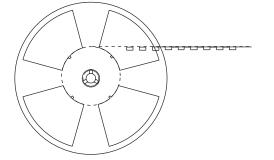
 $0.4^{\pm 0.05}$

 $4.2^{\pm 0.1}$

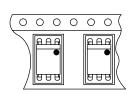


Dimensio	ns List	(Unit : mm)		
а	b	с	d	
330	$17.5^{\pm 1.5}$	100 ^{±1.0}	13 ^{±0.5}	
e	f	g		
23 ^{±1.0}	$2.0^{\pm 0.5}$	2.0 ^{±0.5}		

Direction of product insertion



Pull-out direction



[Packing : 1 000pcs/reel]

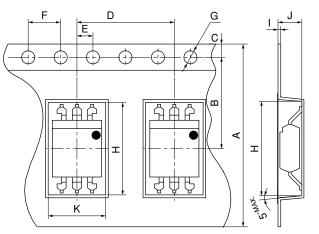


2. Wide SMT Gullwing

Package materials

Carrier tape : A-PET (with anti-static material) Cover tape : PET (three layer system) Reel : PS

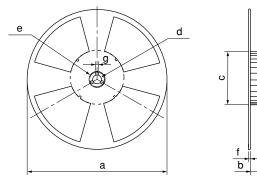
Carrier tape structure and Dimensions



(Unit	:	mm)
	Unit.	•	

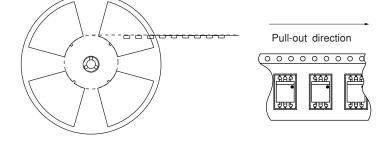
Dimensions List						
В	C	D	Е	F	G	
$11.5^{\pm 0.1}$	$1.75^{\pm 0.1}$	12.0 ^{±0.1}	$2.0^{\pm 0.1}$	$4.0^{\pm 0.1}$	φ1.5 ^{+0.1}	
Ι	J	K				
$0.4^{\pm 0.05}$	$4.1^{\pm 0.1}$	7.6 ^{±0.1}				
	В 11.5 ^{±0.1} І	B C 11.5 ^{±0.1} 1.75 ^{±0.1} I J	$\begin{array}{c ccc} B & C & D \\ \hline 11.5^{\pm 0.1} & 1.75^{\pm 0.1} & 12.0^{\pm 0.1} \\ I & J & K \end{array}$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	B C D E F 11.5 ^{±0.1} 1.75 ^{±0.1} 12.0 ^{±0.1} 2.0 ^{±0.1} 4.0 ^{±0.1} I J K	

Reel structure and Dimensions



Dir	nensio	ns List	(Unit : mm)		
	а	b	с	d	
	330	$25.5^{\pm 1.5}$	$100^{\pm 1.0}$	13 ^{±0.5}	
	e	f	g		
	23 ^{±1.0}	$2.0^{\pm 0.5}$	$2.0^{\pm 0.5}$		

Direction of product insertion



[Packing: 1 000pcs/reel]

SHARP

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- --- Personal computers
- --- Office automation equipment
- --- Telecommunication equipment [terminal]
- --- Test and measurement equipment
- --- Industrial control
- --- Audio visual equipment
- --- Consumer electronics

(ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection with equipment that requires higher reliability such as:

- --- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.

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- --- Telecommunication equipment [trunk lines]
- --- Nuclear power control equipment
- --- Medical and other life support equipment (e.g., scuba).

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